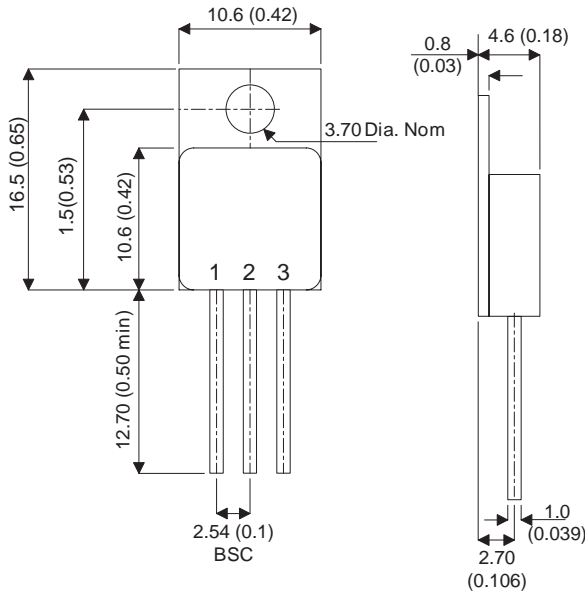


Dimensions in mm (inches).



**P-Channel MOSFET in a Hermetically sealed TO257AB Metal Package.**

**$V_{DSS} = 200V$**

**$I_D = 9.4A$**

**$R_{DS(ON)} = 0.51\Omega$**

All Semelab hermetically sealed products can be processed in accordance with the requirements of BS, CECC and JAN, JANTX, JANTXV and JANS specifications.

**TO257AB (TO220M)**

**PINOUTS**

1 – Gate      2 – Drain      Case – Source

	Parameter	Min.	Typ.	Max.	Units
$V_{DSS}$	Drain – Source Breakdown Voltage			200	V
$I_D$	Continuous Drain Current			9.4	A
$P_D$	Power Dissipation			100	W
$R_{DS(ON)}$	Static Drain – Source On–State Resistance			0.51	$\Omega$
$C_{ISS}$	Input Capacitance		1200		pF
$Q_g$	Total Gate Charge			60	nC
$t_{td(on)}$	Turn–On Delay Time			35	ns
$t_r$	Rise Time			85	ns
$t_{td(off)}$	Turn–Off Delay Time			85	ns
$t_f$	Fall Time			65	ns

This is a shortform datasheet. For a full datasheet please contact [sales@semelab.co.uk](mailto:sales@semelab.co.uk).

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use.